



DL4933 THRU DL4937

SURFACE MOUNT FAST RECOVERY RECTIFIER

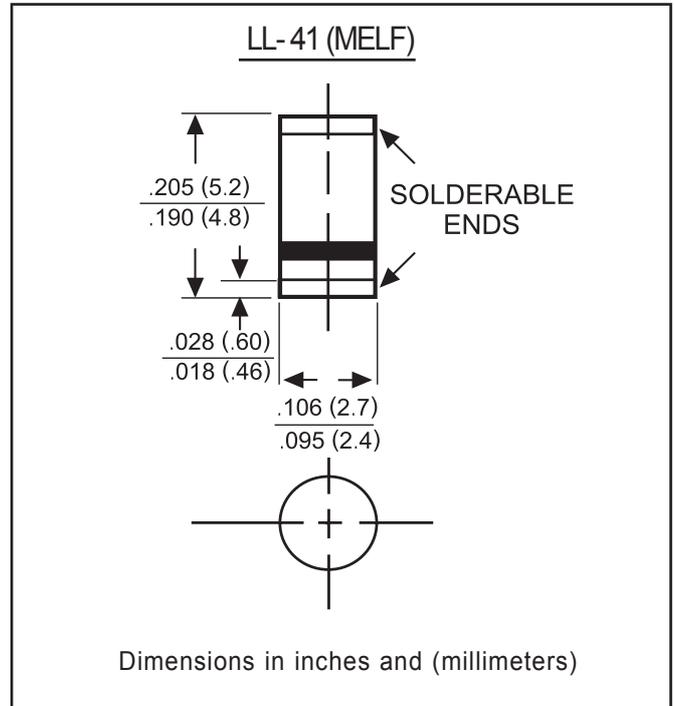
Reverse Voltage - 50 to 600 Volts Forward Current - 1.0 Ampere

FEATURES

- Ideal for surface mounted applications
- Low leakage current
- Glass passivated junction

MECHANICAL DATA

Case: Molded plastic
 EPOXY: UL 94V-0 rate flame retardant
 Terminals : Solder plated solderable per
 MIL-STD-202E, Method 208 guaranteed
 Mounting Position: Any
 Weight : 0.12 grams



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
 Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Characteristic	SYMBOLS	DL 4933	DL 4934	DL 4935	DL 4936	DL 4937	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	V
Maximum average forward rectified current 0.375" (9.5mm) lead length at $T_A=75^\circ\text{C}$	$I_{(AV)}$	1.0					A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	30.0					A
Maximum instantaneous forward voltage at 1.0A	V_F	1.2					V
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	I_R	5.0 50.0					μA
Maximum reverse recovery time (NOTE 1)	t_{rr}	200					ns
Typical junction capacitance (NOTE 2)	C_J	15.0					pF
Typical thermal resistance (NOTE 3)	$R_{\theta JA}$	50.0					$^\circ\text{C/W}$
Operating junction and storage temperature range	T_J, T_{STG}	-65 to +150					$^\circ\text{C}$

Note: 1. Reverse recovery condition $I_F=0.5\text{A}, I_R=1.0\text{A}, I_{rr}=0.25\text{A}$
 2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
 3. Thermal resistance from junction to ambient at 0.24" (6.0mm) lead length, P.C.B. mounted



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RATINGS AND CHARACTERISTIC CURVES

FIG. 1 - TYPICAL FORWARD CURRENT DERATING CURVE

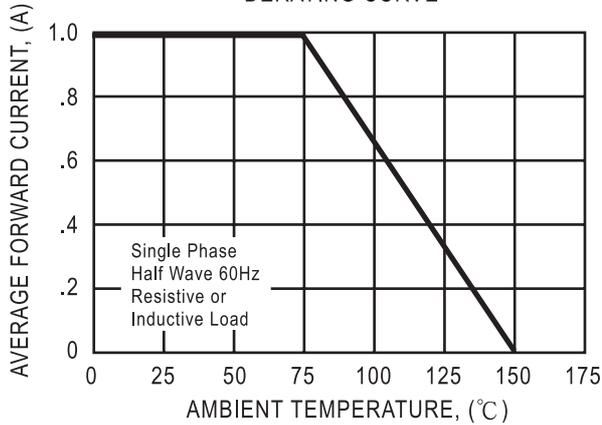


FIG. 2 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

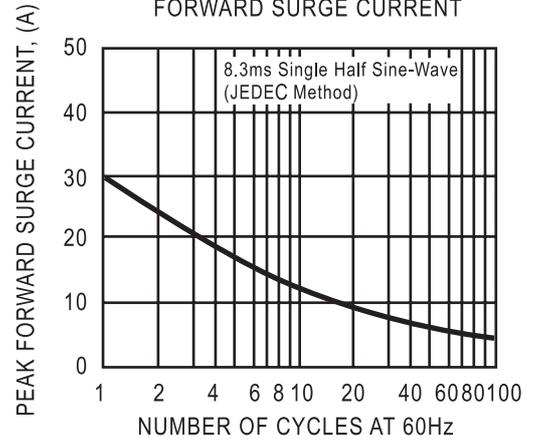


FIG. 3 - TYPICAL JUNCTION CAPACITANCE

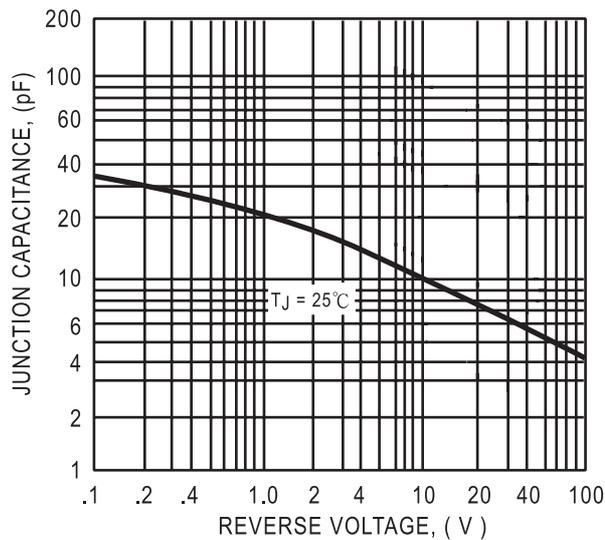


FIG. 4 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

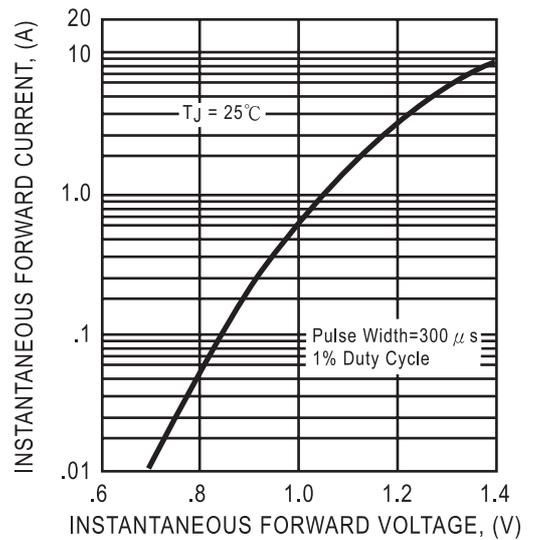
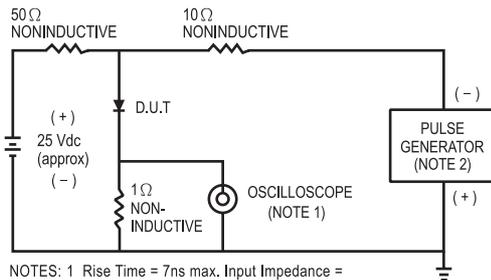


FIG. 5 - TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



- NOTES: 1 Rise Time = 7ns max. Input Impedance = 1 megohm. 22pF.
2. Rise Time = 10ns max. Source Impedance = 50 ohms.

